TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1357

Strobe Flash Applications Audio Power Amplifier Applications

• $h_{FE(1)} = 100 \text{ to } 320 \text{ (VCE} = -2 \text{ V, IC} = -0.5 \text{ A)}$

• $h_{FE(2)} = 70 \text{ (min) } (V_{CE} = -2 \text{ V}, I_{C} = -4 \text{ A})$

• Low saturation voltage: $V_{CE (sat)} = -1.0 \text{ V (max)}$

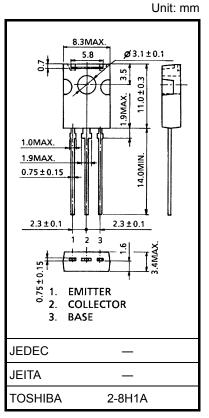
(IC = -4 A, IB = -0.1 A)

• High power dissipation: $P_C = 10 \text{ W} \text{ (Tc} = 25^{\circ}\text{C)},$

 $P_{C} = 1.5 \text{ W (Ta} = 25^{\circ}\text{C)}$

Absolute Maximum Ratings (Tc = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|-----------------------------|--------------------|------------------|------------|------|--|
| Collector-base voltage | | V_{CBO} | -35 | V | |
| Collector-emitter voltage | | V _{CEO} | -20 | V | |
| Emitter-base voltage | | V _{EBO} | -8 | V | |
| Collector current | DC | IC | -5 | А | |
| | Pulsed (Note 1) | I _{CP} | -8 | | |
| Base current | | IB | -1 | Α | |
| Collector power dissipation | Ta = 25°C | Da | 1.5 | W | |
| | Tc = 25°C | P _C | 10 | | |
| Junction temperature | | Tj | 150 | °C | |
| Storage temperature range | | T _{stg} | -55 to 150 | °C | |



Weight: 0.82 g (typ.)

Note 1: Pulse test: Pulse width = 10 ms (max)
Duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

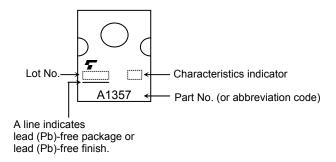
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Tc = 25°C)

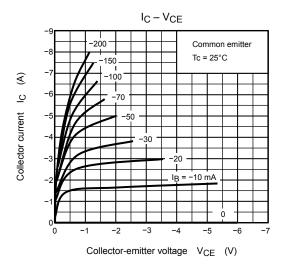
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|---------------------------------|--|-----|------|------|------|
| Collector cut-off current | I _{CBO} | $V_{CB} = -35 \text{ V}, I_{E} = 0$ | _ | _ | -100 | μΑ |
| Emitter cut-off current | I _{EBO} | V _{EB} = -8 V, I _C = 0 | _ | _ | -100 | μΑ |
| Collector-emitter breakdown voltage | V (BR) CEO | I _C = -10 mA, I _B = 0 | -20 | _ | _ | V |
| DC current gain | h _{FE (1)} (Note 3) | V _{CE} = -2 V, I _C = -0.5 A | 100 | _ | 320 | |
| | h _{FE (2)} | V _{CE} = -2 V, I _C = -4 A | 70 | _ | _ | |
| Collector-emitter saturation voltage | V _{CE} (sat) | I _C = -4 A, I _B = -0.1 A | _ | _ | -1.0 | V |
| Base-emitter voltage | V_{BE} | V _{CE} = -2 V, I _C = -4 A | _ | _ | -1.5 | V |
| Transition frequency | f _T | V _{CE} = -2 V, I _C = -0.5 A | _ | 170 | _ | MHz |
| Collector output capacitance | C _{ob} | V _{CB} = -10 V, I _E = 0, f = 1 MHz | _ | 62 | _ | pF |

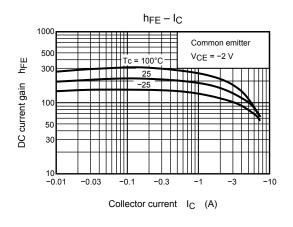
Note 3: $h_{FE(1)}$ classification O: 100 to 200, Y: 160 to 320

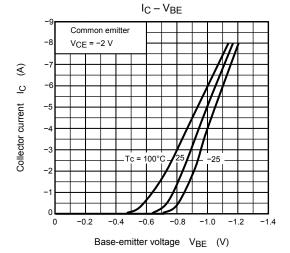
Marking

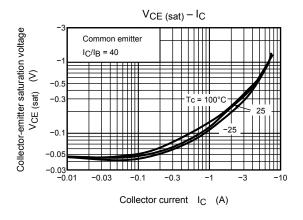


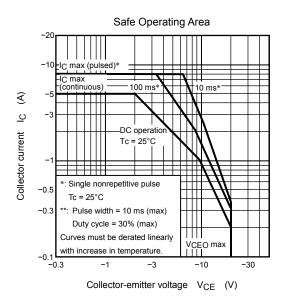
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